

L Number	Hits	Search Text	DB	Time stamp
-	479	349/113	USPAT	2002/02/06 12:09
-	635	349/139	USPAT	2002/02/05 08:58
-	175	349/147	USPAT	2002/02/05 08:58
-	0	(liquid adj crystal) and ((amorphous same passivat\$) same elctrode) and flicker	USPAT	2002/02/05 09:08
-	280	349/139 and amorphous	USPAT	2004/01/07 16:46
-	25	(liquid adj crystal) and (amorphous same passivat\$) and flicker	USPAT	2002/02/05 11:35
-	2	349/113 and amorphous and flicker	USPAT	2002/02/05 10:22
-	998	(liquid adj crystal) and reflect\$ and flicker	USPAT	2002/02/05 10:24
-	44	(liquid adj crystal) and reflect\$ and flicker and passivation	USPAT	2002/02/05 10:25
-	5	("4470669" "4761058" "5075796" "5115336" "5157541").PN.	USPAT	2002/02/05 10:28
-	14	349/147 and (amorphous same passivation)	USPAT	2002/02/05 11:05
-	102	349/113 and amorphous	USPAT	2002/02/05 11:36
-	28	349/139 and (amorphous same passivation)	USPAT	2002/02/05 14:26
-	42	349/113 and ((Silicon adj oxide) and polyimide)	USPAT	2002/02/05 18:24
-	45	349/113 and ((Silicon adj oxide)or SiO2) and polyimide	USPAT	2002/02/05 18:41
-	2	"L45" same (align\$ or passivation)	USPAT	2002/02/05 18:43
-	0	(349/113 and (align\$ same ((silicon adj oxide) or SiO2))) same passivat\$	USPAT	2002/02/06 09:12
-	9	(349/113 and (align\$ same ((silicon adj oxide) or SiO2)))	USPAT	2002/02/06 09:12
-	9	349/113 and (((silicon adj oxide)or SiO2) same align\$)	USPAT	2002/02/06 12:11
-	86	349/139 and amorphous and resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:57
-	1	6532053.pn.	USPAT	2004/01/07 20:50
-	9419	conductive and amorphous and resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:57
-	1407	amorphous near10 resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:59
-	174	(amorphous near10 resistivity) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 21:00